

# 2SC2898

Silicon NPN Triple Diffused

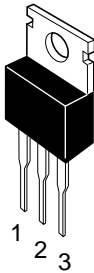
# HITACHI

## Application

High voltage, high speed and high power switching

## Outline

TO-220AB



1. Base
2. Collector (Flange)
3. Emitter

## Absolute Maximum Ratings (Ta = 25°C)

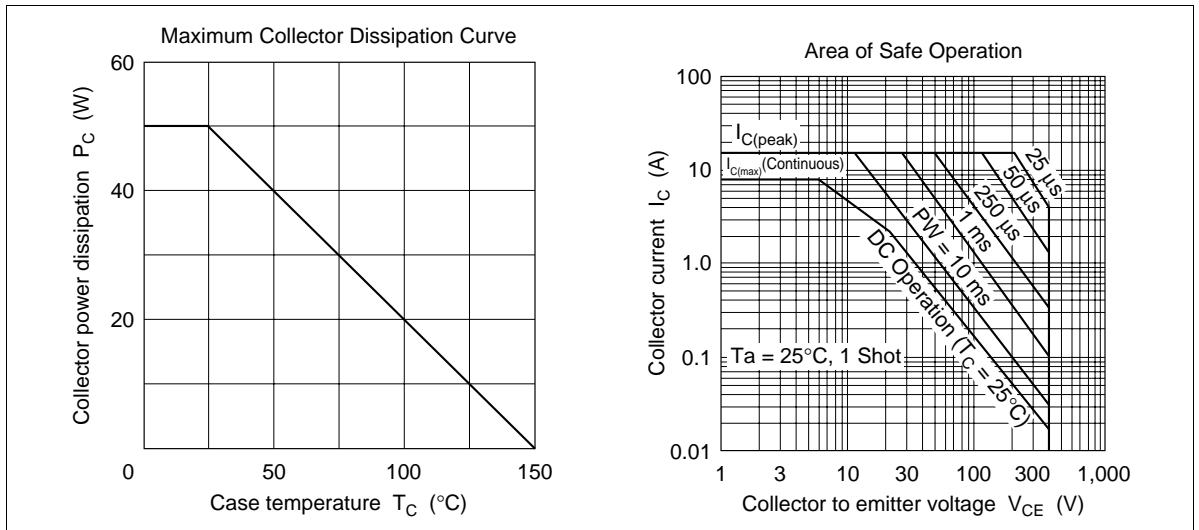
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	500	V
Collector to emitter voltage	$V_{CEO}$	400	V
Emitter to base voltage	$V_{EBO}$	7	V
Collector current	$I_C$	8	A
Collector peak current	$I_{C(peak)}$	16	A
Base current	$I_B$	4	A
Collector power dissipation	$P_C^{*1}$	50	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

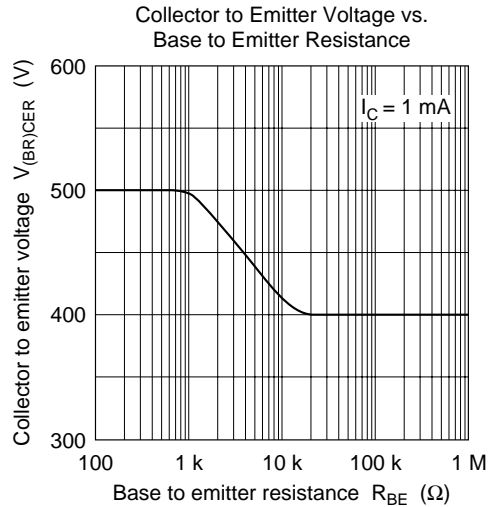
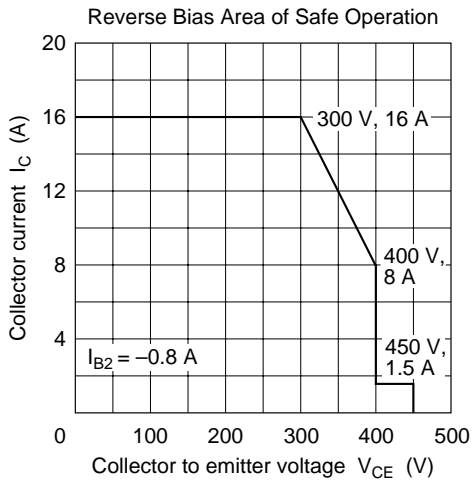
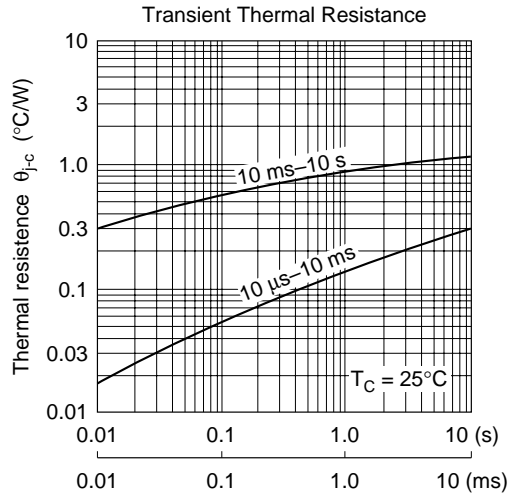
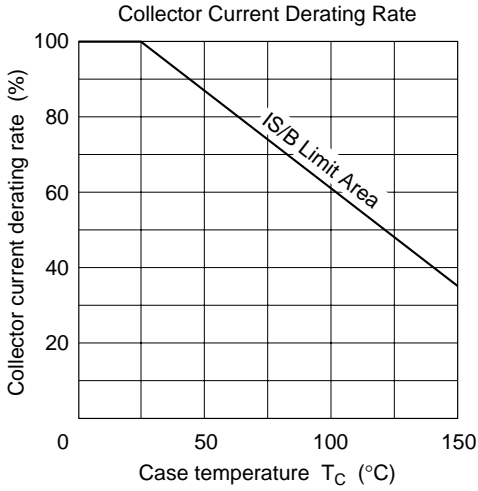
Note: 1. Value at  $T_C = 25^\circ\text{C}$ .

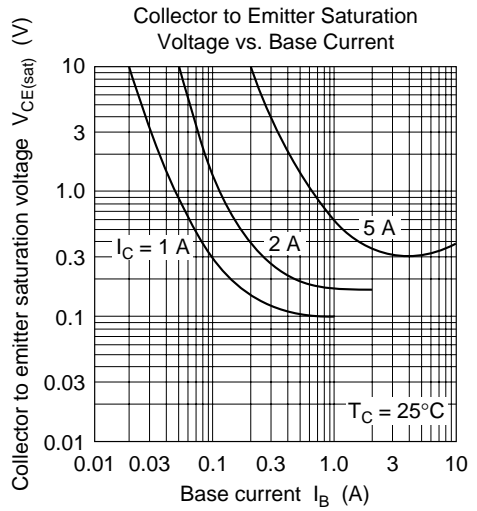
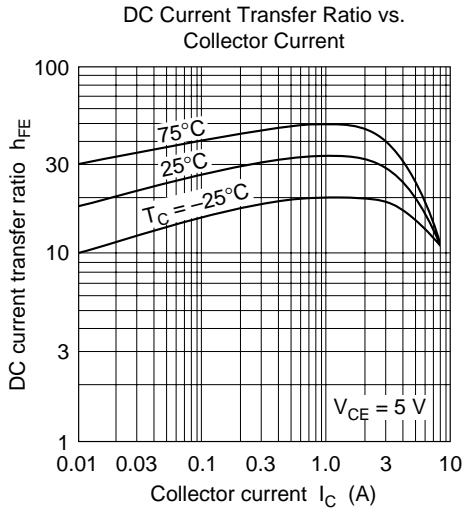
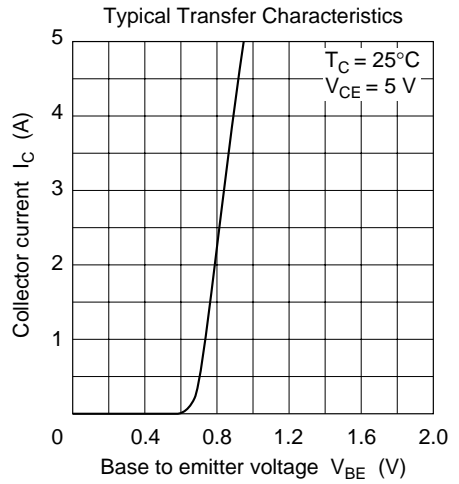
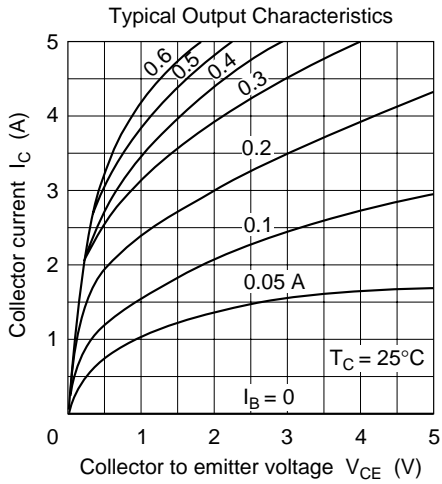
## Electrical Characteristics (Ta = 25°C)

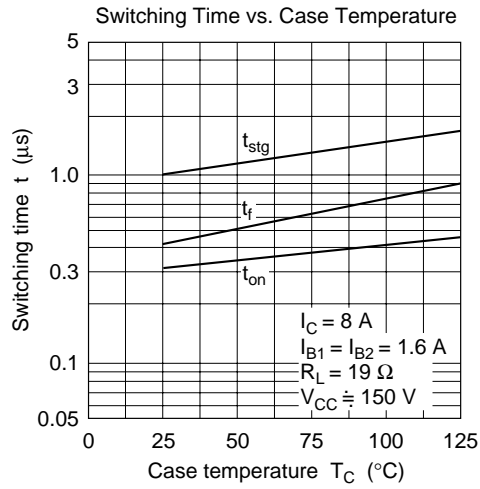
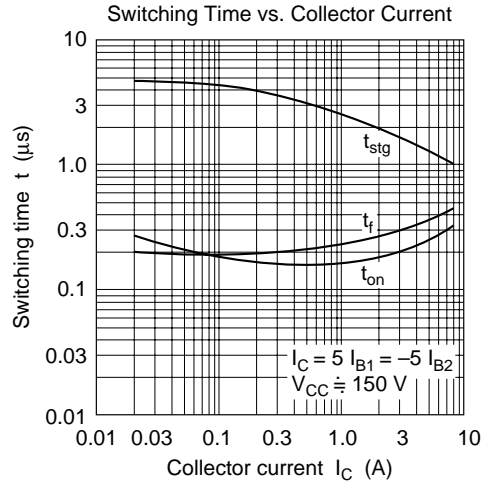
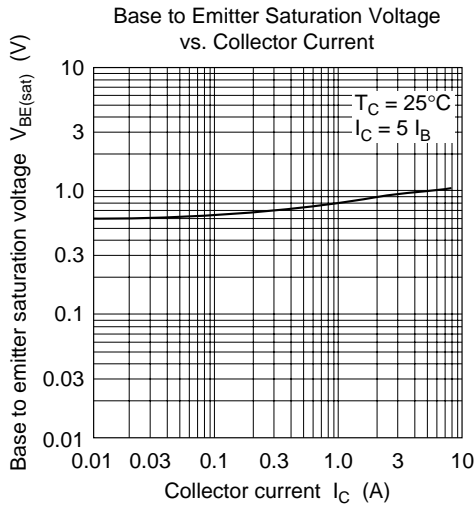
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter sustain voltage	$V_{CEO(sus)}$	400	—	—	V	$I_C = 0.2 \text{ A}$ , $R_{BE} = \infty$ , $L = 100 \text{ mH}$
Collector to emitter sustain voltage	$V_{CEX(sus)}$	400	—	—	V	$I_C = 8 \text{ A}$ , $I_{B1} = 1.6 \text{ A}$ , $I_{B2} = -0.8 \text{ A}$ , $V_{BE} = -5 \text{ V}$ , $L = 180 \mu\text{H}$ , Clamped
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	—	—	V	$I_E = 10 \text{ mA}$ , $I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	50	$\mu\text{A}$	$V_{CB} = 400 \text{ V}$ , $I_E = 0$
	$I_{CEO}$	—	—	50	$\mu\text{A}$	$V_{CE} = 350 \text{ V}$ , $R_{BE} = \infty$
DC current transfer ratio	$h_{FE1}$	15	—	—		$V_{CE} = 5 \text{ V}$ , $I_C = 4 \text{ A}^{*1}$
	$h_{FE2}$	7	—	—		$V_{CE} = 5 \text{ V}$ , $I_C = 8 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	V	$I_C = 4 \text{ A}$ , $I_B = 0.8 \text{ A}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	
Turn on time	$t_{on}$	—	—	0.8	$\mu\text{s}$	$I_C = 8 \text{ A}$ , $I_{B1} = -I_{B2} = 1.6 \text{ A}$ ,
Storage time	$t_{stg}$	—	—	2.0	$\mu\text{s}$	$V_{CC} \cong 150 \text{ V}$
Fall time	$t_f$	—	—	0.8	$\mu\text{s}$	

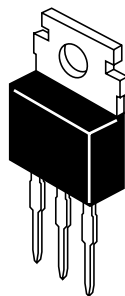
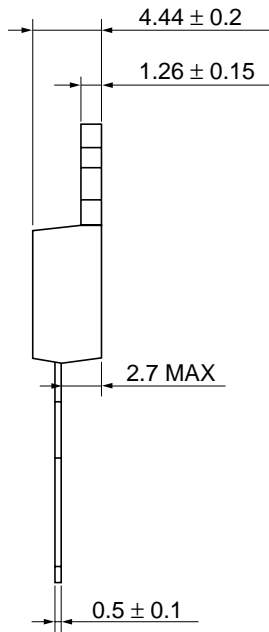
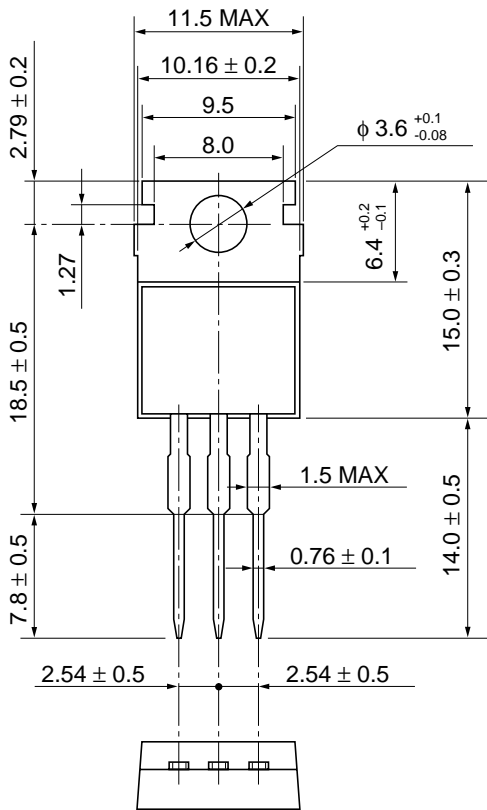
Note: 1. Pulse test











Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.8 g

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# HITACHI

## Hitachi, Ltd.

Semiconductor & Integrated Circuits.  
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan  
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL      North America      : <http://semiconductor.hitachi.com/>  
             Europe                 : <http://www.hitachi-eu.com/hel/ecg>  
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## For further information write to:

Hitachi Semiconductor  
(America) Inc.  
179 East Tasman Drive,  
San Jose, CA 95134  
Tel: <1> (408) 433-1990  
Fax: <1>(408) 433-0223

Hitachi Europe GmbH  
Electronic components Group  
Dornacher Straße 3  
D-85622 Feldkirchen, Munich  
Germany  
Tel: <49> (89) 9 9180-0  
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.  
Electronic Components Group.  
Whitebrook Park  
Lower Cookham Road  
Maidenhead  
Berkshire SL6 8YA, United Kingdom  
Tel: <44> (1628) 585000  
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.  
16 Collyer Quay #20-00  
Hitachi Tower  
Singapore 049318  
Tel: 535-2100  
Fax: 535-1533

Hitachi Asia Ltd.  
Taipei Branch Office  
3F, Hung Kuo Building, No.167,  
Tun-Hwa North Road, Taipei (105)  
Tel: <886> (2) 2718-3666  
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.  
Group III (Electronic Components)  
7/F., North Tower, World Finance Centre,  
Harbour City, Canton Road, Tsim Sha Tsui,  
Kowloon, Hong Kong  
Tel: <852> (2) 735 9218  
Fax: <852> (2) 730 0281  
Telex: 40815 HITEC HX

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